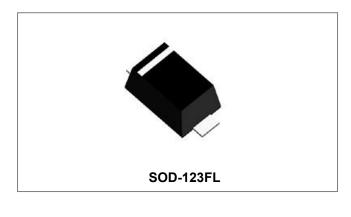




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RS1AL THRU RS1ML SINGLE PHASE 1.0AMP SURFACE MOUNT FAST RECOVERY RECTIFIER



Features Glass passivated device

- Ideal for surface mouted applications
- Low reverse leakage
- Metallurgically bonded construction
- High temperature soldering guaranteed: 260 C/10 seconds,0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension
- Plastic material-UL flammability 94V-0
- This is a Halogen Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Data

- Case: SOD-123FL, molded plastic
- Terminals: Plated leads, solderable per MIL-STD-750, Method 2026
- Polarity: Color band dentes cathode end
- Mounting Position: Any

Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Anode

Type Number	Symbol	RS1 AL	RS1 BL	RS1 DL	RS1 GL	RS1 JL	RS1 KL	RS1 ML	Units
Marking Code		R1AL	R1BL	R1DL	R1GL	R1JL	R1KL	R1ML	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V _{R(RMS)}	35	70	140	280	420	560	700	
Average Rectified Output Current @T _A =30°C	lo	1.0				Α			
Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	30.0				A			
Forward Voltage @I _F = 1.0A, T _J =25°C	VF	1.3			V				
Maximum DC reverse current $T_A = 25^{\circ}C$ at rated DC blocking voltage $T_A = 100^{\circ}C$	I _R	5.0 100					μA		
Typical junction capacitance (Note 1)	CJ	15				pF			
Maximum Reverse Recovery Time (Note 2)	Trr	150		250	5	00	ns		
Typical thermal resistance (Note 3)	R _{0JA}	85				°C/W			
Operating junction and storage temperature range	T _J ,T _{STG}	-55 to +150			°C				

Note: 1. Measured at 1.0 MHZ and applied reverse voltage of 4.0 VDC

2. Measured with I_F =0.5A, I_R =1.0A, I_{rr} =0.25A,

3. Thermal resistance from junction to ambient at 0.375" (9.5mm)lead length, P.C.B. Mounted

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Circuit Diagram

Cathode (



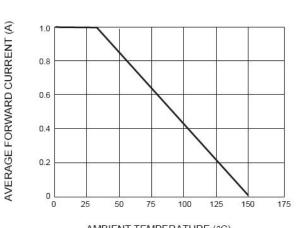
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Ratings and Characteristics Curves

FIG. 1- FORWARD CURRENT DERATING CURVE





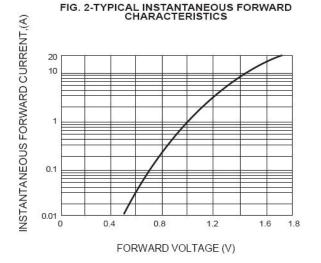
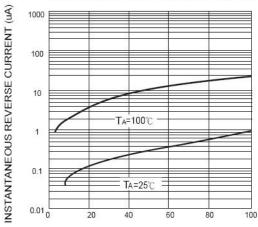
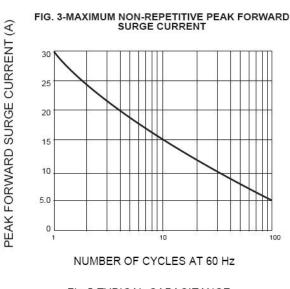
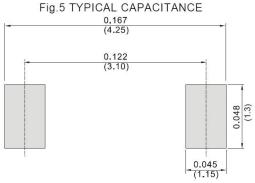


FIG. 4-TYPICAL REVERSE CHARACTERISTICS



PERCENT OF RATED PEAK REVERSE VOLYAGE(%)





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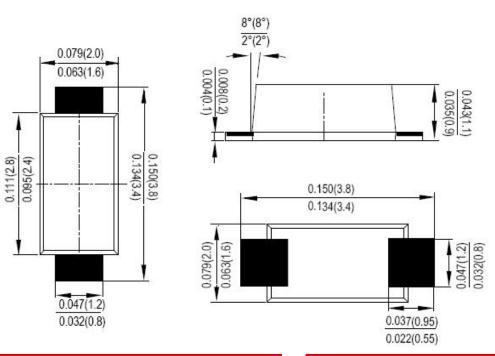


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Mechanical Dimensions SOD-123FL(Inches/Millimeters)

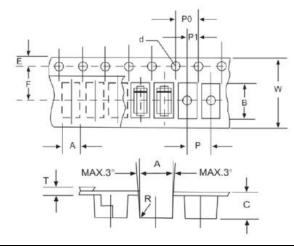


Ordering Information

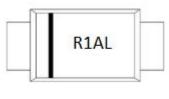
Device	Package	Shipping			
RS1AL					
THRU	SOD-123FL	3000pcs / reel			
RS1ML					
RS1ALTR					
THRU	SOD-123FL	3000pcs / reel			
RS1MLTR					

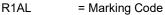
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Carrier Tape Specification SOD-123FL



Marking Diagram





SYMBOL	Millimeters			
STWBUL	Min.	Max.		
A	1.95	2.15		
В	3.85	4.05		
С	1.35	1.55		
d	1.50	1.60		
E	1.65	1.85		
F	3.40	3.60		
Р	3.90	4.10		
P0	3.90	4.10		
P1	1.90	2.10		
W	7.90	8.30		

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